HEF4027B

Dual JK flip-flop

Rev. 9 — 18 November 2011

Product data sheet

1. **General description**

The HEF4027B is a edge-triggered dual JK flip-flop which features independent set-direct (SD), clear-direct (CD), clock (CP) inputs and outputs (Q, Q). Data is accepted when CP is LOW, and transferred to the output on the positive-going edge of the clock. The active HIGH asynchronous clear-direct (CD) and set-direct (SD) inputs are independent and override the J, K, and CP inputs. The outputs are buffered for best system performance. Schmitt trigger action makes the clock input highly tolerant of slower rise and fall times.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to $V_{\text{DD}},\,V_{\text{SS}},$ or another input.

2. **Features and benefits**

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

Applications

- Registers
- Counters
- Control circuits

Ordering information 4.

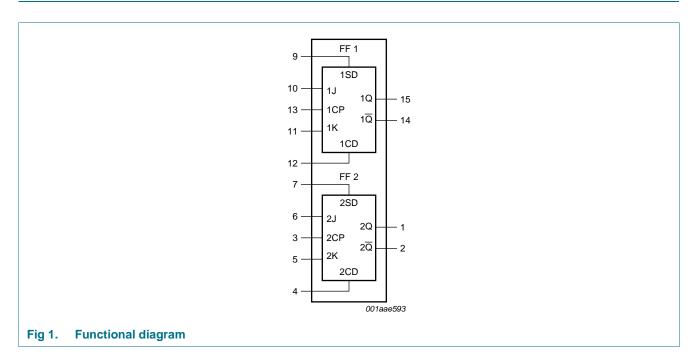
Table 1. **Ordering information**

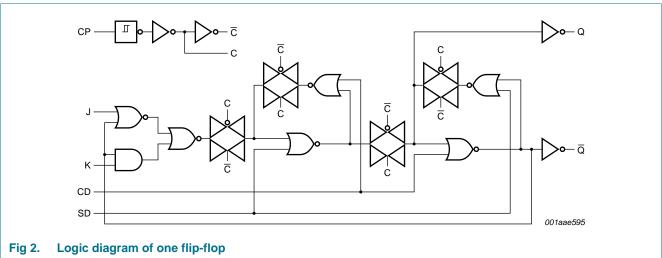
 T_{amb} from -40 °C to +85 °C.

Type number	Package	Package							
	Name	Description	Version						
HEF4027BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4						
HEF4027BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1						



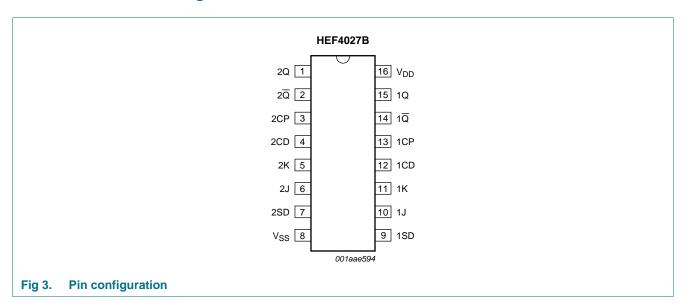
5. Functional diagram





6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
V_{SS}	8	ground supply voltage
1SD, 2SD	9, 7	asynchronous set-direct input (active HIGH)
1J, 2J	10, 6	synchronous input
1K, 2K	11, 5	synchronous input
1CD, 2CD	12, 4	asynchronous clear-direct input (active HIGH)
1CP, 2CP	13, 3	clock input (LOW-to-HIGH edge-triggered)
1Q, 2Q	14, 2	complement output
1Q, 2Q	15, 1	true output
V_{DD}	16	supply voltage

7. Functional description

Table 3. Function table[1]

Inputs		Outputs				
nSD	nCD	nCP	nJ	nK	nQ	nQ
Н	L	X	X	X	Н	L
L	Н	X	X	X	L	Н
Н	Н	X	X	X	Н	Н

Table 3. Function table 1... continued

Inputs	Outputs					
nSD	nCD	nCP	nJ	nK	nQ	nQ
L	L	\uparrow	L	L	no change	no change
L	L	↑	Н	L	Н	L
L	L	\uparrow	L	Н	L	Н
L	L	\uparrow	Н	Н	nQ	nQ

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.; $\uparrow = positive\text{-going transition.}$

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I_{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$	-	±10	mA
V_{I}	input voltage		-0.5	$V_{DD} + 0.5$	V
I_{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I _{I/O}	input/output current		-	±10	mA
I_{DD}	supply current		-	50	mA
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature	in free air	-40	+85	°C
P _{tot}	total power dissipation	T_{amb} –40 °C to +85 °C			
		DIP16 package	<u>[1]</u> _	750	mW
		SO16 package	[2] _	500	mW
Р	power dissipation	per output	-	100	mW

^[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		3	15	V
VI	input voltage		0	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5 V$	-	3.75	μs/V
		$V_{DD} = 10 \text{ V}$	-	0.5	μs/V
		V _{DD} = 15 V	-	0.08	μs/V

^[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$ V; $V_I = V_{SS}$ or V_{DD} ; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	-40 °C	T _{amb} =	25 °C	T _{amb} =	85 °C	Unit
				Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	$ I_{O} < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level input voltage	$ I_{O} < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V_{OH}	HIGH-level output voltage	$ I_O < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V_{OL}	LOW-level output voltage	$ I_O < 1 \mu A$	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level output current	$V_0 = 2.5 \text{ V}$	5 V	-	-1.7	-	-1.4	-	-1.1	mΑ
		$V_0 = 4.6 \text{ V}$	5 V	-	-0.52	-	-0.44	-	-0.36	mΑ
		$V_0 = 9.5 \text{ V}$	10 V	-	-1.3	-	-1.1	-	-0.9	mΑ
		$V_0 = 13.5 \text{ V}$	15 V	-	-3.6	-	-3.0	-	-2.4	mΑ
I_{OL}	LOW-level output current	$V_O = 0.4 V$	5 V	0.52	-	0.44	-	0.36	-	mΑ
		$V_0 = 0.5 \ V$	10 V	1.3	-	1.1	-	0.9	-	mΑ
		$V_0 = 1.5 \text{ V}$	15 V	3.6	-	3.0	-	2.4	-	mΑ
I _I	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μΑ
I_{DD}	supply current	$I_O = 0 A$	5 V	-	4.0	-	4.0	-	30	μΑ
			10 V	-	8.0	-	8.0	-	60	μΑ
			15 V	-	16.0	-	16.0	-	120	μΑ
C _I	input capacitance		-	-	-	-	7.5	-	-	pF

11. Dynamic characteristics

Table 7. Dynamic characteristics

 $V_{SS} = 0 \text{ V; } T_{amb} = 25 \text{ °C; for test circuit see } Figure 7; unless otherwise specified.}$

Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula[1]	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	$CP \rightarrow Q, \overline{Q};$	5 V	78 ns + $(0.55 \text{ ns/pF})C_L$	-	105	210	ns
	propagation delay	see <u>Figure 4</u>	10 V	29 ns + (0.23 ns/pF)C _L	-	40	80	ns
			15 V	22 ns + (0.16 ns/pF)C _L	-	30	60	ns
		$CD \rightarrow Q$;	5 V	93 ns + (0.55 ns/pF)C _L	-	120	240	ns
		see <u>Figure 4</u>	10 V	33 ns + (0.23 ns/pF)C _L	-	45	90	ns
			15 V	27 ns + (0.16 ns/pF)C _L	-	35	70	ns
		$SD \rightarrow \overline{Q}$;	5 V	113 ns + (0.55 ns/pF)C _L	-	140	280	ns
		see Figure 4	10 V	44 ns + (0.23 ns/pF)C _L	-	55	110	ns
			15 V	32 ns + (0.16 ns/pF)C _L	-	40	80	ns
t _{PLH}	LOW to HIGH	$CP \rightarrow Q, \overline{Q};$	5 V	58 ns + $(0.55 \text{ ns/pF})C_L$	-	85	170	ns
	propagation delay	see Figure 4	10 V	27 ns + (0.23 ns/pF)C _L	-	35	70	ns
			15 V	22 ns + (0.16 ns/pF)C _L	-	30	60	ns
		$CD \rightarrow \overline{Q}$;	5 V	48 ns + (0.55 ns/pF)C _L	-	75	150	ns
		see Figure 4	10 V	24 ns + (0.23 ns/pF)C _L	-	35	70	ns
			15 V	17 ns + (0.16 ns/pF)C _L	-	25	50	ns
		$SD \rightarrow Q$; see <u>Figure 4</u>	5 V	43 ns + (0.55 ns/pF)C _L	-	70	140	ns
			10 V	19 ns + (0.23 ns/pF)C _L	-	30	60	ns
			15 V	17 ns + (0.16 ns/pF)C _L	-	25	50	ns
t _t	transition time	Insition time see Figure 4	5 V [2]	10 ns + (1.00 ns/pF)C _L	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF)C _L	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C _L	-	20	40	ns
t _{su}	set-up time	$J,K\toCP;$	5 V		50	25	-	ns
		see Figure 5	10 V		30	10	-	ns
			15 V		20	5	-	ns
t _h	hold time	$J,K\toCP;$	5 V		25	0	-	ns
		see <u>Figure 5</u>	10 V		20	0	-	ns
			15 V		15	5	-	ns
W	pulse width	CP LOW;	5 V		80	40	-	ns
		minimum width	10 V		30	15	-	ns
		see Figure 5	15 V		24	12	-	ns
		SD, CD HIGH;	5 V		90	45	-	ns
		minimum width	10 V		40	20	-	ns
		see Figure 6	15 V		30	15	-	ns
rec	recovery time	SD, CD inputs;	5 V		+20	-15	-	ns
		see Figure 6	10 V		+15	-10	-	ns
			15 V		+10	-5		

 Table 7.
 Dynamic characteristics ...continued

 $V_{SS} = 0 \text{ V}$; $T_{amb} = 25 \,^{\circ}\text{C}$; for test circuit see <u>Figure 7</u>; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula[1]	Min	Тур	Max	Unit
f_{max}	maximum	CP input;	5 V		4	8	-	MHz
	frequency	J = K = HIGH; see Figure 5	10 V		12	25	-	MHz
		see <u>rigure s</u>	15 V		15	30	-	MHz

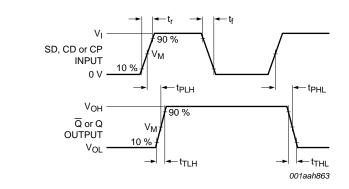
- [1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).
- [2] t_t is the same as t_{TLH} and t_{THL} .

Table 8. Dynamic power dissipation P_D

 P_D can be calculated from the formulas shown. $V_{SS} = 0$ V; $t_r = t_f \le 20$ ns; $T_{amb} = 25$ °C.

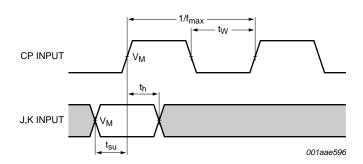
Symbol	Parameter	V_{DD}	Typical formula for P_D (μW)	Where:
P_D	dynamic power	5 V	$P_D = 900 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	f _i = input frequency in MHz;
dissipation	10 V	$P_D = 4500 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	f _o = output frequency in MHz;	
		15 V	$P_D = 13200 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	C _L = output load capacitance in pF;
				V_{DD} = supply voltage in V;
				$\Sigma(f_0 \times C_L)$ = sum of the outputs.

12. Waveforms



 V_{OH} and V_{OL} are typical output voltages levels that occur with the output load. Measurement points are given in Table 9.

Fig 4. Waveforms showing rise, fall and transition times and propagation delays



Measurement points are given in Table 9.

Fig 5. Waveforms showing set-up and hold times and minimum clock pulse width

HEF4027B

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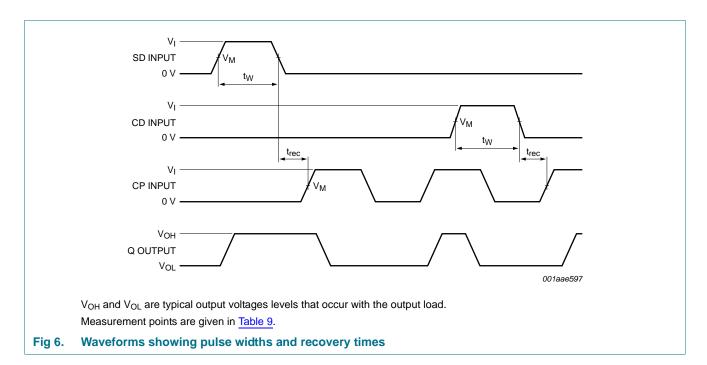


Table 9. Measurement points

Supply voltage	Input	Output
V_{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}

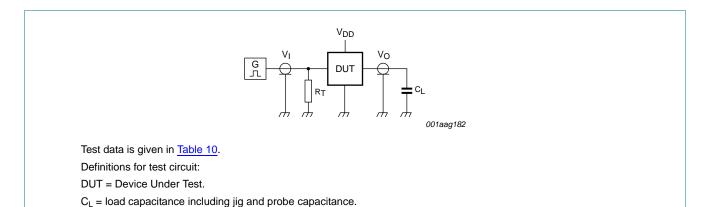


Fig 7. Test circuit

Table 10. Test data

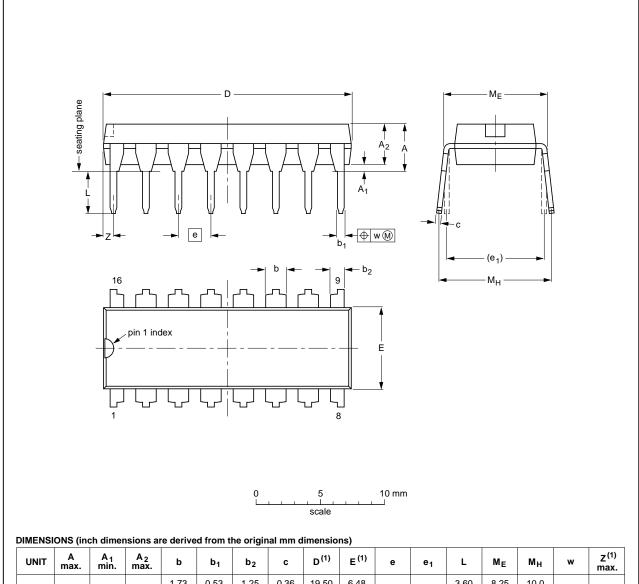
Supply voltage	Input	Load	
V _{DD}	V _I	t _r , t _f	C _L
5 V to 15 V	V _{SS} or V _{DD}	≤ 20 ns	50 pF

 R_T = termination resistance should be equal to the output impedance Z_0 of the pulse generator.

13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

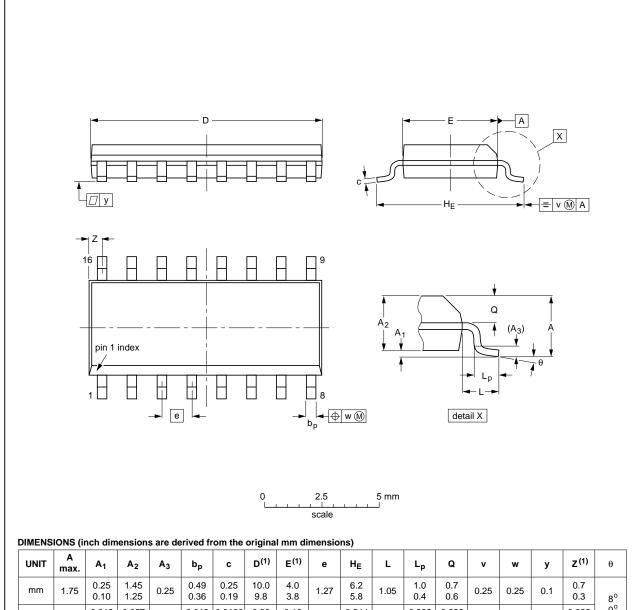
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT38-4						95-01-14 03-02-13	

Fig 8. Package outline SOT38-4 (DIP16)

HEF4027B

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	l	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig 9. Package outline SOT109-1 (SO16)

HEF4027B

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4027B v.9	20111118	Product data sheet	-	HEF4027B v.8
Modifications:	 Legal pages 	s updated.		
	 Changes in 	"General description" and "	Features and benefits".	
HEF4027B v.8	20111010	Product data sheet	-	HEF4027B v.7
HEF4027B v.7	20091125	Product data sheet	-	HEF4027B v.6
HEF4027B v.6	20090624	Product data sheet	-	HEF4027B v.5
HEF4027B v.5	20081110	Product data sheet	-	HEF4027B v.4
HEF4027B v.4	20080703	Product specification	-	HEF4027B_CNV v.3
HEF4027B_CNV v.3	19950101	Product specification	-	HEF4027B_CNV v.2
HEF4027B_CNV v.2	19950101	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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Dual JK flip-flop

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